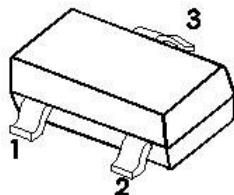


SOT-23 贴片塑封开关二极管
SOT-23 Plastic-Encapsulate Switching Diode

特征 Features

SOT-23



开关速度小于 4nS; Fast Switching Device (TRR <4nS)

最大功率耗散 225mW; Power Dissipation of 225mW

高稳定性和可靠性。High Stability and High Reliability

反向漏电流小。Low reverse leakage

机械数据 Mechanical Data

封装: SOT-23 封装 SOT-23 Small Outline Plastic Package

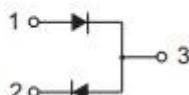
环氧树脂UL 易燃等级Epoxy UL: 94V-0

安装位置: 任意 Mounting Position: Any

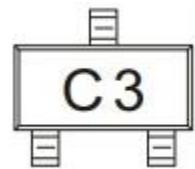
印字Marking: C3

1. BASE

2. Emitter



3. COLLECTOR



极限值和温度特性(TA = 25°C 除非另有规定)

Maximum Ratings & Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

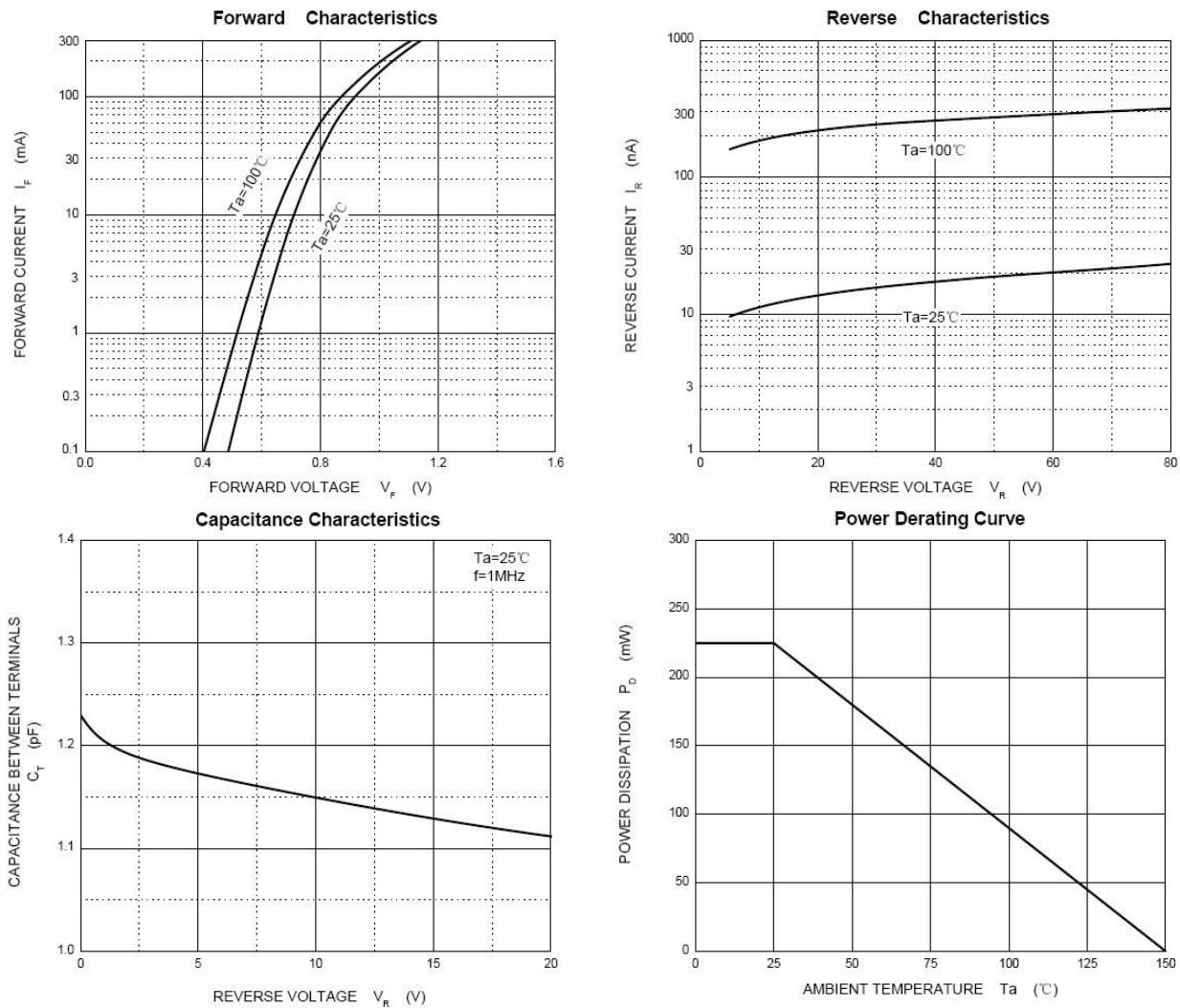
参数 Parameters	符号 Symbol	数值 Value	单位 Unit
反向电压 Reverse Voltage	VR	85	V
功率消耗 Power Dissipation	Pd	225	mW
工作结温 Operating junction temperature	Tj	150	°C
存储温度 Storage temperature range	Ts	-65~+150	°C
平均整流电流 Average Rectified Current	Io	200	mA
正向(不重复)电流 Non-repetitive Peak Forward Current	IFM	400	mA
正向(不重复)浪涌电流 Peak Forward Surge Current @tp=1ms; TA=25°C	IFSM	2.0	A
典型热阻 Typical thermal resistance	RθJA	500	°C/W

Valid provided that electrodes are kept at ambient temperature.

电 特 性 Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified).

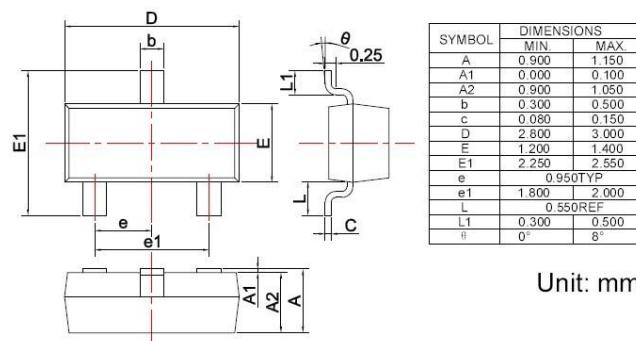
符号 Symbols	参数 Parameter	测试条件 Test Condition	界限 Limits		单位 Unit
			Min	Max	
VRB	反向击穿电压 Reverse Voltage	IB=100uA	85	---	V
IR	反向漏电电流 Reverse Leakage Current	VR=80V	---	2.5	uA
VF	正向电压 Forward Voltage	IF=1mA	---	0.715	V
		IF=10mA	---	0.855	
		IF=100mA	---	1.00	
TRR	反向恢复时间 Reverse Recovery Time	IF= IR=10mA, RL=100Ω IRR=0.1xIR	---	4	nS
CT	结电容 Capacitance	VR=0V, f=1MHZ	---	3	pF

Typical Characteristics



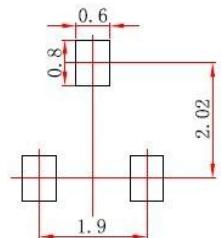
SOT-23 PACKAGE OUTLINE

Plastic surface mounted package



Unit: mm

焊盘设计参考 Precautions: PCB Design(Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs)



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.